

RoHS

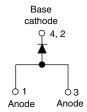
COMPLIANT

HALOGEN

FREE

Schottky Rectifier, 5.5 A





D-PAK	(TO-252AA)

PRODUCT SUMMARY					
Package	D-PAK (TO-252AA)				
I _{F(AV)}	5.5 A				
V _R	100 V				
V _F at I _F	See Electrical table				
I _{RM}	4 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Single die				
E _{AS}	6 mJ				

FEATURES

- Low forward voltage drop
- · Guard ring for enhanced ruggedness and long term reliability



- · Small foot print, surface mountable
- · High frequency operation
- AEC-Q101 qualified
- ık
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

A Mosta MCI Javal 1 mar J CTD 000 J E maximum no	
 Meets MSL level 1, per J-STD-020, LF maximum pe of 260 °C 	eak

DESCRIPTION

The VS-50WQ10FNHM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	5.5	А				
V_{RRM}		100	V				
I _{FSM}	t _p = 5 μs sine	330	А				
V _F	5 A _{pk} , T _J = 125 °C	0.63	V				
TJ	Range	- 40 to 150	°C				

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-50WQ10FNHM3	UNITS			
Maximum DC reverse voltage	V_{R}	100	V			
Maximum working peak reverse voltage	V_{RWM}	100	V			

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS		
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 135 °C	5.5			
Maximum peak one cycle non-repetitive surge current	l	5 μs sine or 3 μs rect. pulse Following any rated load condition and with rated		330	Α	
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	110		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 0.5 A, L = 40 mH		6.0	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		0.5	А	



ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS			
		5 A	T _{.1} = 25 °C	0.77	V	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	11 = 23 0	0.91		
See fig. 1	VFM (1)	5 A	T 105 °C	0.63		
		10 A	T _J = 125 °C	0.74		
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C		1	mA	
See fig. 2	IRM (**	T _J = 125 °C	V _R = Rated V _R	4	IIIA	
Threshold voltage	V _{F(TO)}			0.47	V	
Forward slope resistance	r _t	$T_J = T_J$ maximum		21.46	mΩ	
Typical junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz), 25 °C 183			pF	
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 5.0			nH	

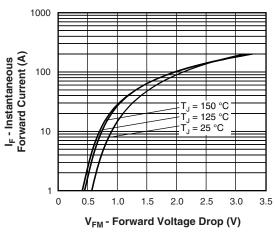
Note

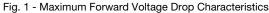
 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	3.0	°C/W		
Approximate weight			0.3	g		
Approximate weight			0.01	oz.		
Marking device		Case style D-PAK	50WQ	10FNH		

Note

(1)
$$\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$$
 thermal runaway condition for a diode on its own heatsink





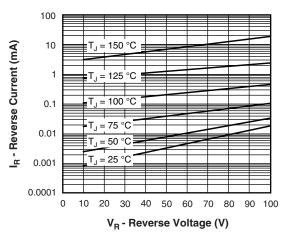


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

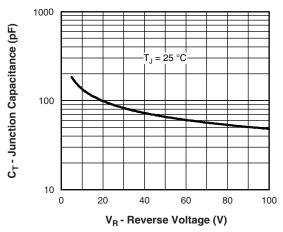


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

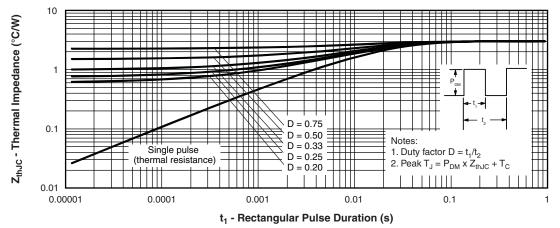


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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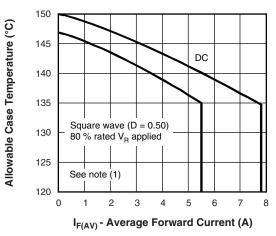


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

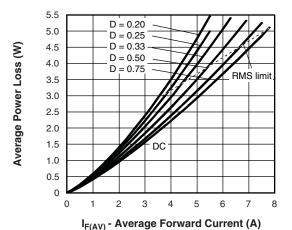


Fig. 6 - Forward Power Loss Characteristics

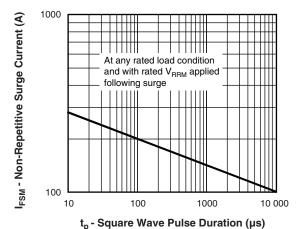


Fig. 7 - Maximum Non-Repetitive Surge Current

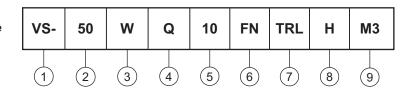
Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (5.5 A)

Package identifier:

W = D-PAK

4 - Schottky "Q" series

Voltage rating (10 = 100 V)

6 - FN = TO-252AA (D-PAK)

7 - • None = Tube

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

8 - H = AEC-Q101 qualified

9 - Environmental digit:

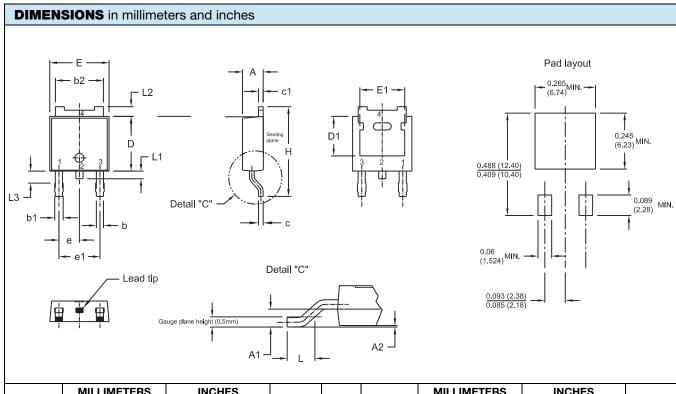
M3 = Halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-50WQ10FNHM3	75	3000	Antistatic plastic tube			
VS-50WQ10FNTRHM3	2000	2000	13" diameter reel			
VS-50WQ10FNTRRHM3	3000	3000	13" diameter reel			
VS-50WQ10FNTRLHM3	3000	3000	13" diameter reel			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95519			
Part marking information	www.vishay.com/doc?95518			
Packaging information	www.vishay.com/doc?95033			



D-PAK (TO-252AA)



SYMBOL	MILLIN	MILLIMETERS		INCHES	
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	2.21	2.38	0.087	0.094	
A2	0.03	0.127	0.001	0.005	
b	0.71	0.88	0.028	0.035	
b1	0.76	1.14	0.030	0.045	
b2	5.23	5.44	0.206	0.214	
С	0.46	0.58	0.018	0.023	
C1	0.46	0.58	0.018	0.023	
D	5.97	6.22	0.235	0.2455	
D1	4.32	4.45	0.170	0.175	
Е	6.48	6.73	0.255	0.2655	
E1	4.49	5.50	0.177	0.217	

SYMBOL	MILLIM	IETERS	S INCHES		NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
A1	0.89	1.14	0.035	0.045	
Н	9.65	10.41	0.380	0.410	
L	1.40	1.78	0.055	0.070	
е	2.28	2.28 BSC		0.09 BSC	
e1	4.57 BSC		0.18 BSC		
L1	0.64	1.02	0.025	0.040	
L2	0.89	1.27	0.035	0.050	
L3	1.15	1.52	0.040	0.060	
	•				

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L3 only for reference
- (3) Dimension D1, E1, L2 and b2 establish a minimum mounting surface for thermal pad
- (4) Dimensions D and E do not include mold flash.
- (5) Outline conforms to JEDEC outline TO-252AA



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